



**Microsemi**

SCOTTSDALE DIVISION

USB0803 thru USB0824

## Unidirectional TVSarray™

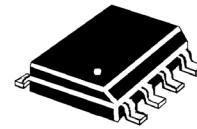
### PRODUCT PREVIEW

#### DESCRIPTION

This TRANSIENT VOLTAGE SUPPRESSOR (TVS) array is packaged in an SO-8 configuration giving protection to 2 Unidirectional data or interface lines. It is designed for use in applications where protection is required at the board level from voltage transients caused by electrostatic discharge (ESD) as defined in IEC 61000-4-2, electrical fast transients (EFT) per IEC 61000-4-4 and effects of secondary lightning.

These TVS arrays have a peak power rating of 500 watts for an 8/20  $\mu$ sec pulse. This array is suitable for protection of sensitive circuitry consisting of TTL, CMOS DRAM's, SRAM's, HCMOS, HSIC microprocessors, **UNIVERSAL SERIAL BUS (USB)** and I/O transceivers. The USB08XX product provides board level protection from static electricity and other induced voltage surges that can damage or upset sensitive circuitry.

#### TVSarray™ SERIES



#### APPLICATIONS

- EIA-RS485 data rate: 5 Mbs
- 10 Base T Ethernet
- USB date rate: 900 Mbs

**IMPORTANT:** For the most current data, consult **MICROSEMI**'s website: <http://www.microsemi.com>

#### FEATURES

- Protects up to 2 unidirectional lines
- Surge protection per IEC 61000-4-2, IEC 61000-4-4
- Provides electrically isolated protection
- UL 94V-0 Flammability Classification
- **LOW CAPACITANCE 5 pF per line pair**
- **LOW LEAKAGE**

#### PACKAGING

- Tape & Reel per EIA Standard 481
- 13 inch reel; 2,500 pieces (OPTIONAL)
- Carrier tubes; 95 pcs (STANDARD)

#### MAXIMUM RATINGS

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Peak Pulse Power: 500 watts (8/20  $\mu$ s, Figure 1)
- Pulse Repetition Rate: < .01%

#### MECHANICAL

- Molded SO-8 Surface Mount
- Weight 0.066 grams (approximate)
- Marking: Logo, device marking code, date code
- Pin #1 defined by dot on top of package

#### ELECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless otherwise specified

PART NUMBER	DEVICE MARKING	STAND OFF VOLTAGE $V_{WM}$	BREAKDOWN VOLTAGE $V_{BR}$ @1 mA	CLAMPING VOLTAGE $V_c$ @ 1 Amp (Figure 2)	CLAMPING VOLTAGE $V_c$ @ 5 Amp (Figure 2)	STANDBY CURRENT $I_d$ @ $V_{WM}$	CAPACITANCE (f=1 MHz) $C$ @0V	TEMPERATURE COEFFICIENT OF $V_{BR}$ $\alpha_{VBR}$
		VOLTS	VOLTS	VOLTS	VOLTS	$\mu$ A	pF	mV/°C
		MAX	MIN	MAX	MAX	MAX	MAX	MAX
USB0803	AF	3.3	4	8	11	200	5	-5
USB0805	AG	5.0	6.0	10.8	13	20	5	1
USB0812	AH	12.0	13.3	19	26	1	5	8
USB0815	AJ	15.0	16.7	24	32	1	5	11
USB0824	AK	24.0	26.7	43	57	1	5	28

Note: Transient Voltage Suppressor (TVS) product is normally selected based on its stand off voltage  $V_{WM}$ . Product selected voltage should be equal to or greater than the continuous peak operating voltage of the circuit to be protected.



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PRODUCT PREVIEW

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### SYMBOLS & DEFINITIONS

Symbol	DEFINITION
$V_{WM}$	Stand Off Voltage: Maximum dc voltage that can be applied over the operating temperature range. $V_{WM}$ must be selected to be equal or be greater than the operating voltage of the line to be protected
$V_{BR}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current
$V_C$	Clamping Voltage: Maximum clamping voltage across the TVS device when subjected to a given current at a pulse time of 20 $\mu$ s.
$I_D$	Standby Current: Leakage current at $V_{WM}$ .
C	Capacitance: Capacitance of the TVS as defined @ 0 volts at a frequency of 1 MHz and stated in picofarads.

### GRAPHS

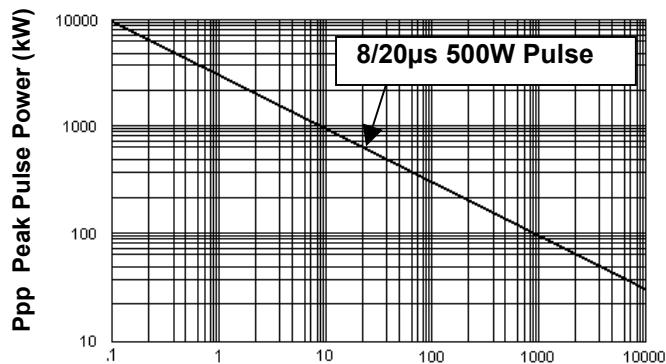


Figure 1  
Peak Pulse Power Vs Pulse Time  $t = \mu$ sec

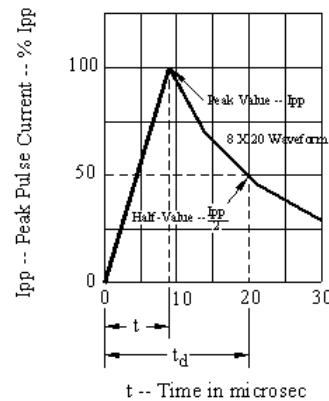
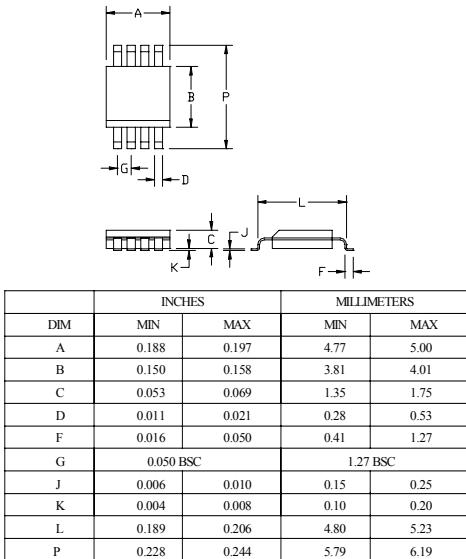
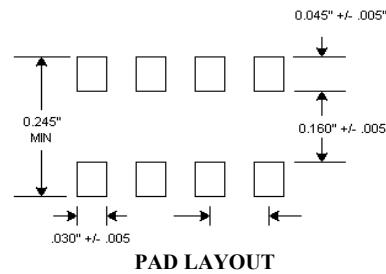


Figure 2  
Pulse Wave Form

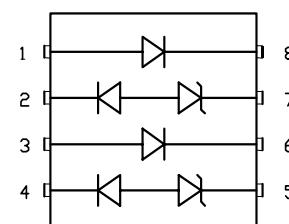
### OUTLINE AND SCHEMATIC



OUTLINE



PAD LAYOUT



SCHEMATIC

GRAPHS PACKAGE  
DATA